

## SCD241



### Power Rectifier Diodes

#### Applications

- Power Supplies
- Uncontrolled Rectifiers
- Battery Chargers

#### Features

- Full blocking capability over wide temperature range
- Hermetic metal case with glass insulator
- Threaded Stud

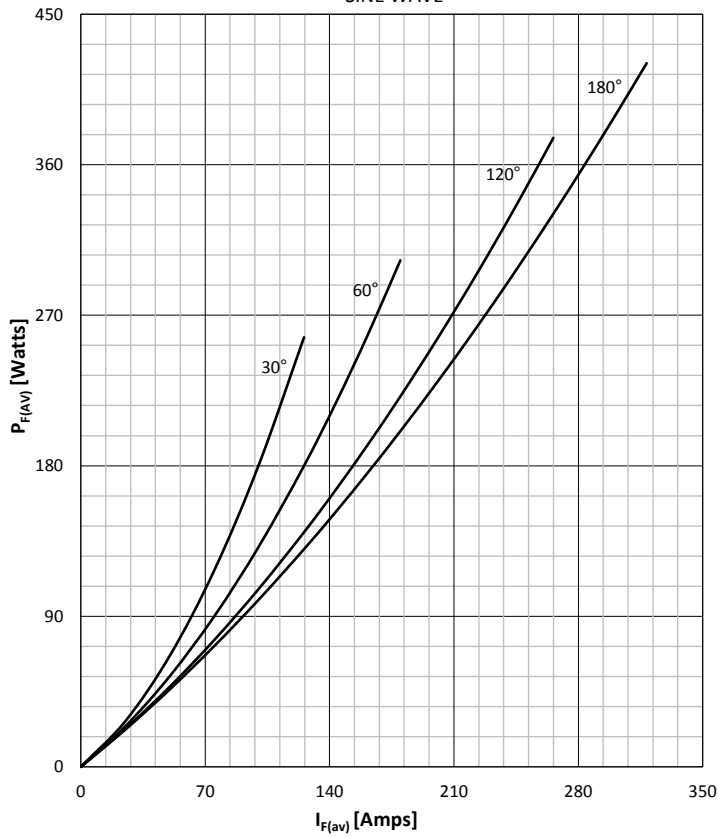
#### Key Parameters

$V_{RRM}$	= 1600V
$I_{F(AV)}$	= 320A
$I_{FSM}$	= 6000A
$V_{F(TO)}$	= 0.85V
$r_F$	= 0.60mΩ

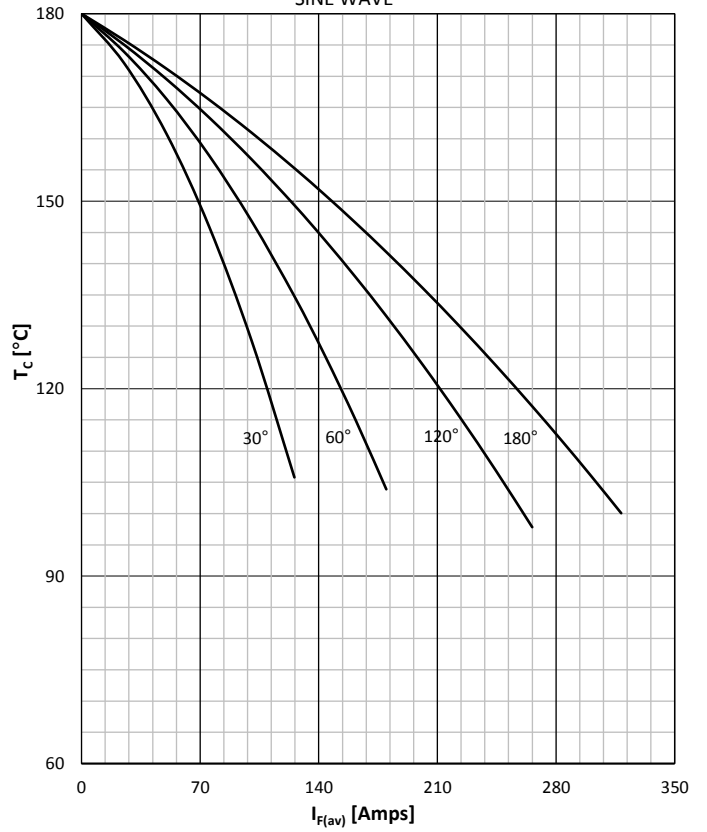
Symbol	Characteristic	Conditions	$T_j$ [°C]	Value	Unit
<b>BLOCKING</b>					
$V_{RRM}$	Repetitive peak reverse voltage		180	200 - 1600	V
$V_{RSM}$	Non-repetitive peak reverse voltage		180	300 - 1700	V
$I_{RRM}$	Repetitive peak reverse current	$V = V_{RRM}$	180	30	mA
<b>CONDUCTING</b>					
$I_{F(AV)}$	Mean forward current	180° sin, 50 Hz, $T_c=100^\circ\text{C}$ $T_c=125^\circ\text{C}$		320 240	A
$I_{FRMS}$	RMS current			500	A
$I_{FSM}$	Surge forward current	Sine wave, 10 ms Without reverse voltage	25	6000	A
			180	5000	A
$I^2 t$	$I^2 t$	Sine wave, 10 ms Without reverse voltage	25	180000	A <sup>2</sup> s
			180	125000	A <sup>2</sup> s
$V_F$	Forward voltage	On-state current = 750A	180	1.30	V
$V_{F(TO)}$	Threshold voltage		180	0.85	V
$r_F$	Forward slope resistance		180	0.60	mΩ
<b>MOUNTING</b>					
$R_{th(j-c)}$	Thermal impedance, sin 180°	Junction to case		0.19	°C/W
$R_{th(c-h)}$	Thermal impedance	Case to heatsink		0.03	°C/W
$T_j$	Max. junction temperature			180	°C
$T_{stg}$	Storage temperature			-40 .... 180	°C
M	Mounting torque			26	NM
W	Weight (Approx.)			250	gm

**DISSIPATION CHARACTERISTICS**

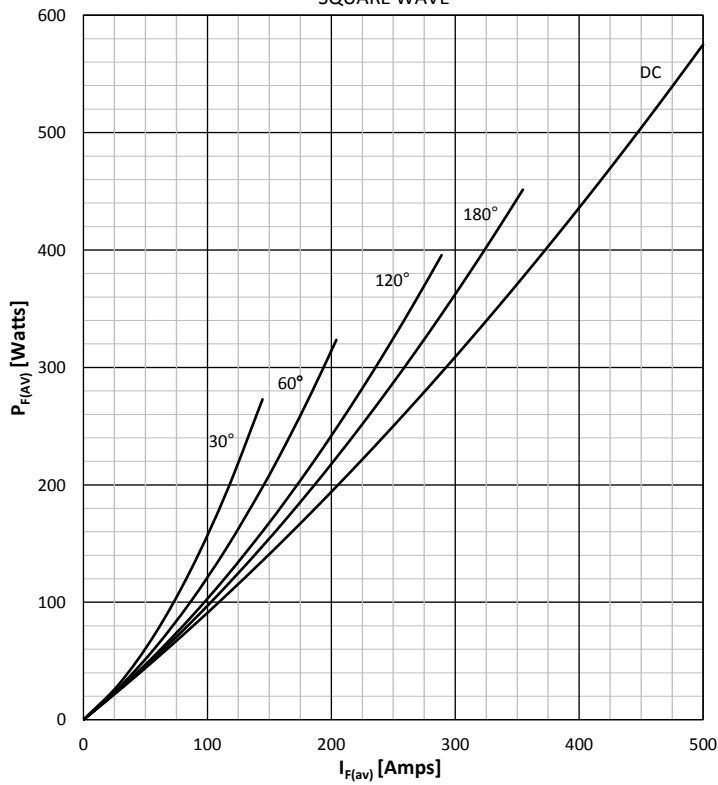
SINE WAVE


**FORWARD CURRENT DERATING CURVE**

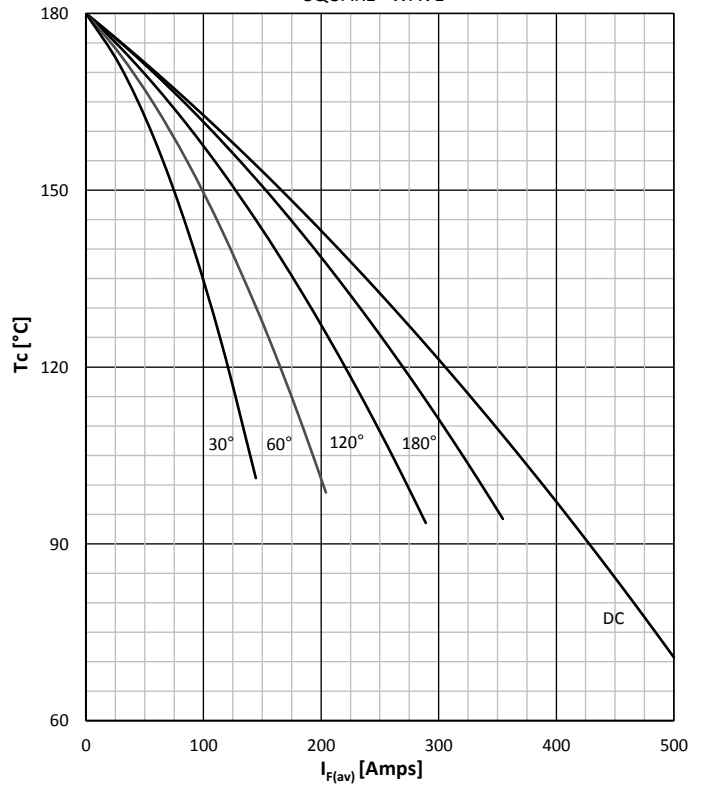
SINE WAVE

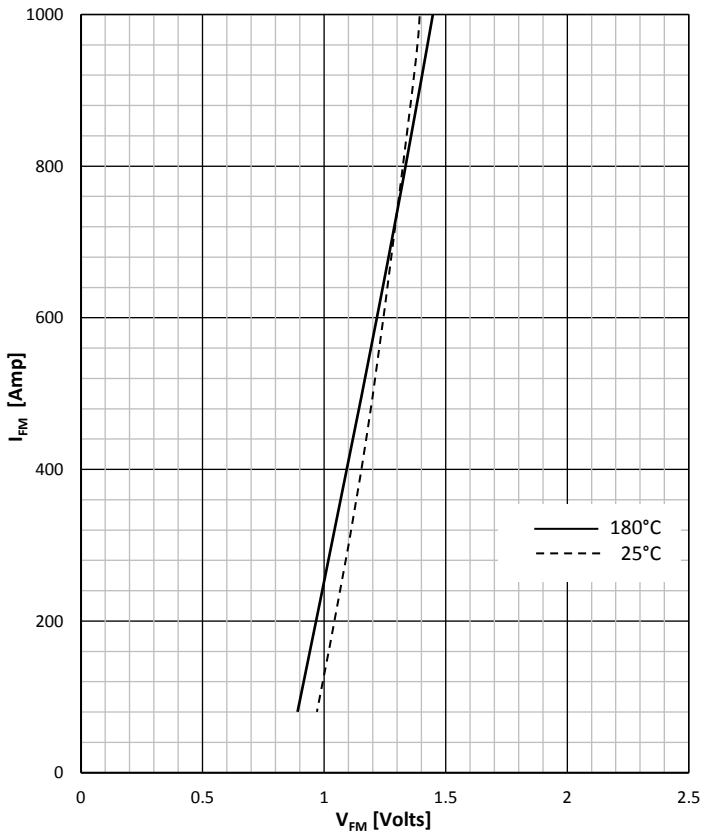
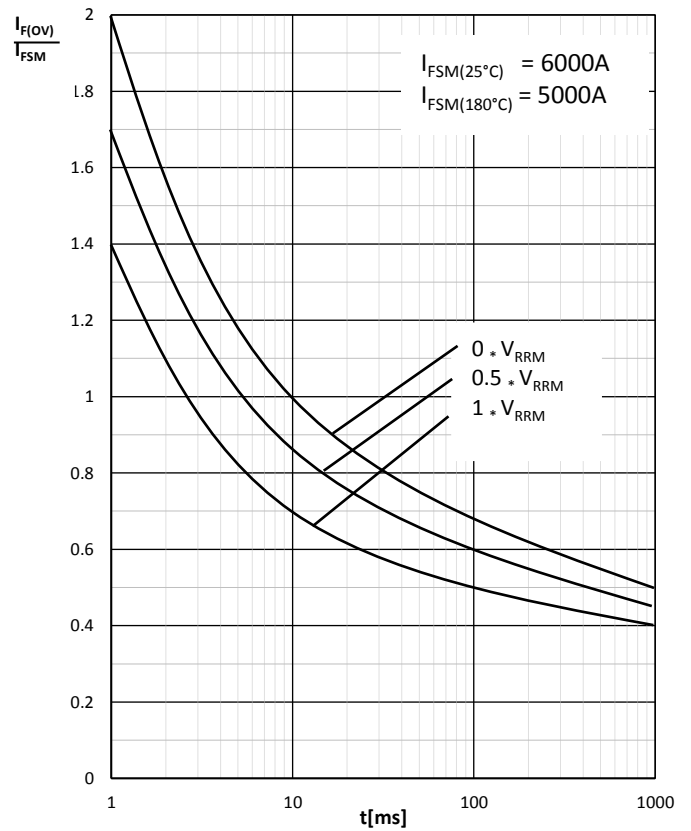
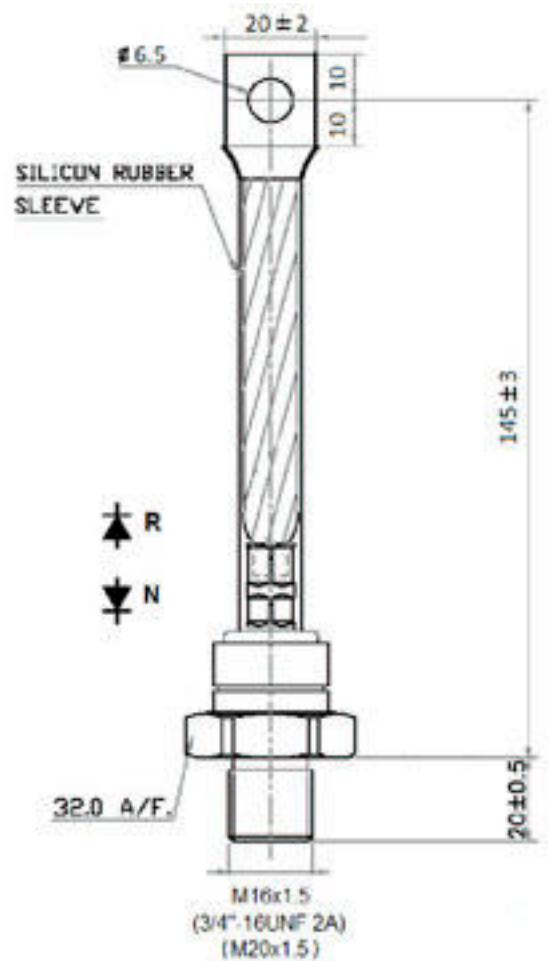
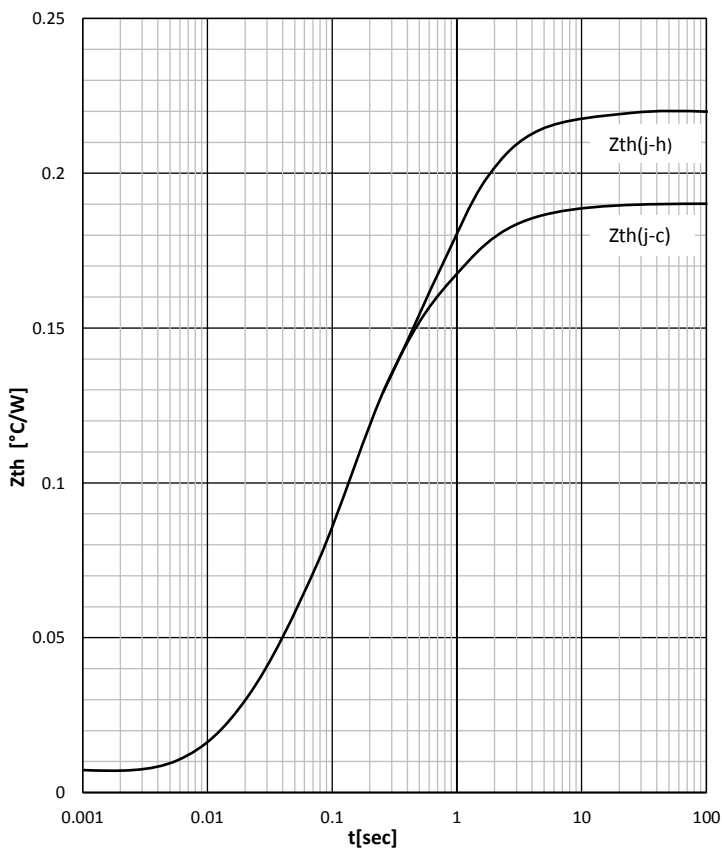

**DISSIPATION CHARACTERISTICS**

SQUARE WAVE


**FORWARD CURRENT DERATING CURVE**

SQUARE WAVE



**FORWARD CHARACTERISTIC**

**SURGE CHARACTERISTICS**

**TRANSIENT THERMAL IMPEDANCE**


Scomes srl reserves the right to change any specification without notice

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